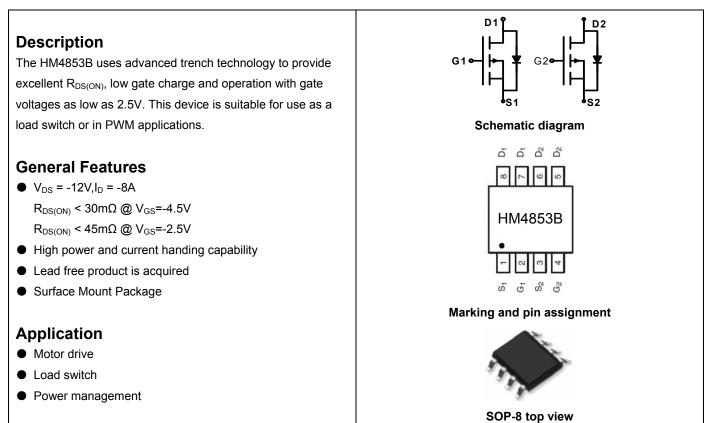


P-Channel Enhancement Mode Power MOSFET



Package Marking And Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
HM4853B	HM4853B	SOP-8	Ø330mm	12mm	2500 units

Absolute Maximum Ratings (T_A=25°Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-12	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous	Ι _D	-8	A
Drain Current-Pulsed (Note 1)	I _{DM}	-24	А
Maximum Power Dissipation	PD	3.1	W
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Desistance lunction to Ambient (Note 2)			
Thermal Resistance, Junction-to-Ambient (10062)	$R_{ heta JA}$	42	°C/W

Electrical Characteristics (T_A=25[°]Cunless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-12	-	-	V



Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-12V,V _{GS} =0V	-	-	-1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±12V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-0.4	-0.65	-1.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-6A	-	21	30	mΩ
Dialit-Source Off-State Resistance		V _{GS} =-2.5V, I _D =-5A		28	45	mΩ
Forward Transconductance	g fs	V _{DS} =-15V,I _D =-6A	-	17	-	S
Dynamic Characteristics (Note4)	·		•	•		
Input Capacitance	Clss	(-10)()(-0)(-	2100	-	PF
Output Capacitance	Coss	- V _{DS} =-10V,V _{GS} =0V, - F=1.0MHz	-	498	-	PF
Reverse Transfer Capacitance	Crss		-	300	-	PF
Switching Characteristics (Note 4)				•		
Turn-on Delay Time	t _{d(on)}		-	25	-	nS
Turn-on Rise Time	tr	V_{DD} =-10V, R _L =10Ω,	-	30	-	nS
Turn-Off Delay Time	t _{d(off)}	V _{GS} =-4.5V,R _{GEN} =6Ω	-	70	-	nS
Turn-Off Fall Time	t _f		-	50	-	nS
Total Gate Charge	Qg		-	17	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =-10V,I _D =-6A,V _{GS} =-4.5V	-	4.1	-	nC
Gate-Drain Charge	Q _{gd}]	-	4.3	-	nC
Drain-Source Diode Characteristics	L	•				
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-8A	-	-	-1.2	V

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

Surface Mounted on FR4 Board, t ≤ 10 sec.
Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.

4. Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

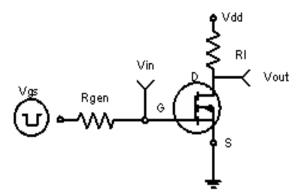
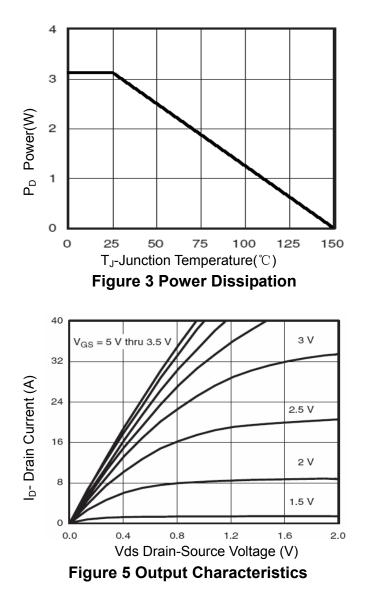
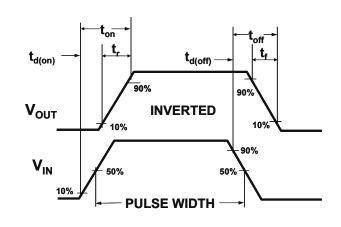
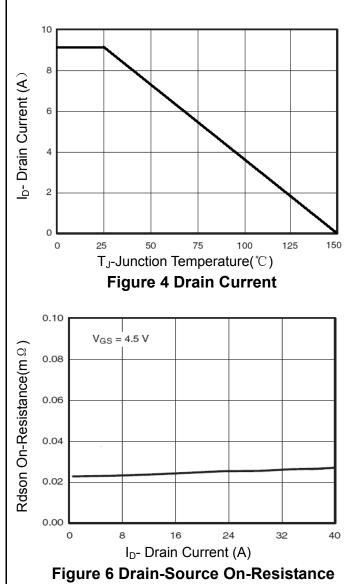


Figure 1 Switching Test Circuit



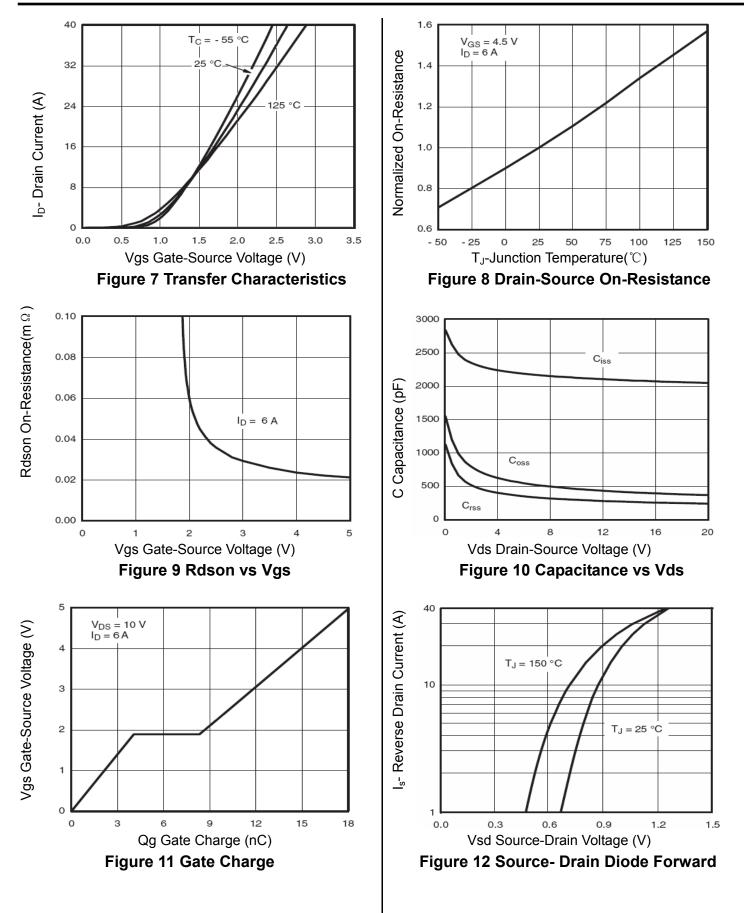








HM4853B





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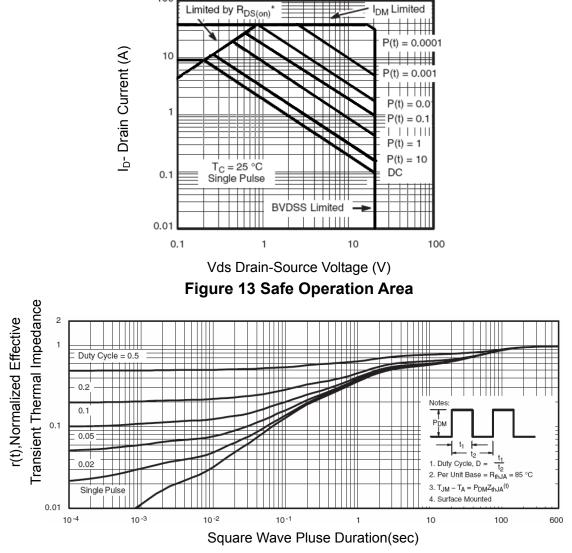
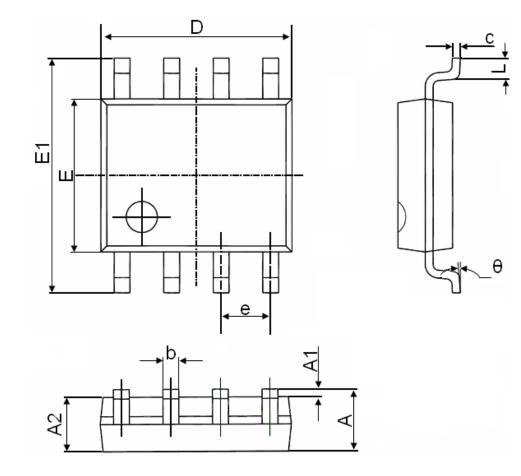


Figure 14 Normalized Maximum Transient Thermal Impedance



SOP-8 Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
с	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
e	1.270(BSC)		0.050	(BSC)	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	



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